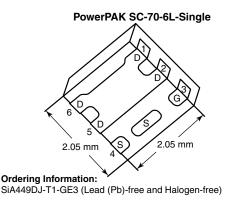


P-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY								
V _{DS} (V)	$R_{DS(on)}(\Omega)$ (Max.)	I _D (A)	Q _g (Typ.)					
	0.020 at V _{GS} = - 10 V	- 12 ^a						
- 30	0.024 at V _{GS} = - 4.5 V	- 12 ^a	23.1 nC					
	0.038 at $V_{GS} = -2.5 \text{ V}$	- 12 ^a						



FEATURES

- TrenchFET® Power MOSFET
- Thermally Enhanced PowerPAK® SC-70 Package
 - Small Footprint Area
 - Low On-Resistance
- 100 % R_a Tested
- Material categorization:

For definitions of compliance please see www.vishay.com/doc?99912

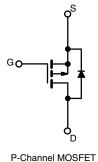


COMPLIANT HALOGEN

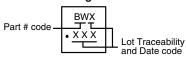
FREE

APPLICATIONS

- Providing low voltage drop in Smart Phones, Tablet PCs, Mobile Computing:
 - Power Management
 - **Charger Switches**
 - Load Switches
 - DC/DC Converters



Marking Code



ABSOLUTE MAXIMUM RATINGS	(T _A = 25 °C, unle	ss otherwise no	oted)		
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 30	v	
Gate-Source Voltage		V _{GS}	± 12		
	T _C = 25 °C		- 12 ^a		
Continuous Drain Current (T. 150 °C)	T _C = 70 °C		- 12 ^a		
Continuous Drain Current (T _J = 150 °C)	T _A = 25 °C	I _D	- 10.4 ^{b, c}		
	T _A = 70 °C		- 8.3 ^{b, c}	Α	
Pulsed Drain Current (t = 300 μs)	•	I _{DM}	- 30		
Continuous Source-Drain Diode Current	T _C = 25 °C		- 12 ^a		
Continuous Source-Drain Diode Current	T _A = 25 °C	I _S	- 2.9 ^{b, c}		
	T _C = 25 °C		19		
Maximum Dawar Dissination	T _C = 70 °C	Ь	12	w	
Maximum Power Dissipation	T _A = 25 °C	P _D	3.5 ^{b, c}	VV	
	T _A = 70 °C		2.2 ^{b, c}		
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	- 55 to 150	°C		
Soldering Recommendations (Peak Temperature	e) ^{d, e}	_	260		

THERMAL RESISTANCE RATINGS									
Parameter		Symbol	Typical	Maximum	Unit				
Maximum Junction-to-Ambient ^{b, f}	t ≤ 5 s	R _{thJA}	28	36	°C/W				
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	5.3	6.5	7 0/**				

Notes:

- a. Package limited
- b. Surface mounted on 1" x 1" FR4 board.
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.
- Maximum under steady state conditions is 80 °C/W.



SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)									
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit			
Static	•			•					
Drain-Source Breakdown Voltage	V_{DS}	V _{GS} = 0, I _D = - 250 μA				V			
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	J 050 A		- 22		\//0C			
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I _D = - 250 μA		3		mV/°C			
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.6		- 1.5	V			
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA			
Zoro Coto Voltogo Drain Current		V _{DS} = - 30 V, V _{GS} = 0 V			- 1	μΑ			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 30 V, V _{GS} = 0 V, T _J = 55 °C			- 10				
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le$ - 5 V, V_{GS} = - 10 V	- 10			Α			
	` '	V _{GS} = - 10 V, I _D = - 6 A		0.0155	0.0200	Ω			
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 5 A		0.0185	0.0240				
	, ,	V _{GS} = - 2.5 V, I _D = - 2 A		0.0264	0.0380				
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 6 A		31		S			
Dynamic ^b	•				'	l			
Input Capacitance	C _{iss}			2140		pF			
Output Capacitance	C _{oss}	V _{DS} = - 15 V, V _{GS} = 0 V, f = 1 MHz		168					
Reverse Transfer Capacitance	C _{rss}			155					
	Q _g	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -10.4 \text{ A}$		48	72	2			
Total Gate Charge				23.1	35	nC			
Gate-Source Charge		V _{DS} = - 15 V, V _{GS} = - 4.5 V, I _D = - 10.4 A		2.5					
Gate-Drain Charge	Q_{gd}			6.2					
Gate Resistance	R _g	f = 1 MHz	0.6	3.3	6.6	Ω			
Turn-On Delay Time	t _{d(on)}			8	16				
Rise Time	t _r	$V_{DD} = -15 \text{ V, R}_{L} = 1.8 \Omega$		10	20	ns			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -8.3 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		39	60				
Fall Time	t _f			8	16				
Turn-On Delay Time	t _{d(on)}			26	40				
Rise Time	t _r	$V_{DD} = -15 \text{ V, R}_{L} = 1.8 \Omega$		28	42				
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -8.3 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$		44	66				
Fall Time	t _f			8	16				
Drain-Source Body Diode Characterist	·				I	l			
Continuous Source-Drain Diode Current	Is	T _C = 25 °C			- 12	_			
Pulse Diode Forward Current	I _{SM}	-			- 30	A			
Body Diode Voltage	V _{SD}	I _S = - 8.3 A, V _{GS} = 0		- 0.8	- 1.2	V			
Body Diode Reverse Recovery Time	t _{rr}			19	30	ns			
Body Diode Reverse Recovery Charge	Q _{rr}			12	20	nC			
Reverse Recovery Fall Time	ta	$I_F = -8.3 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		12		- ns			
Reverse Recovery Rise Time	t _b			7					
	-D			, , , , , , , , , , , , , , , , , , ,	l				

Notes:

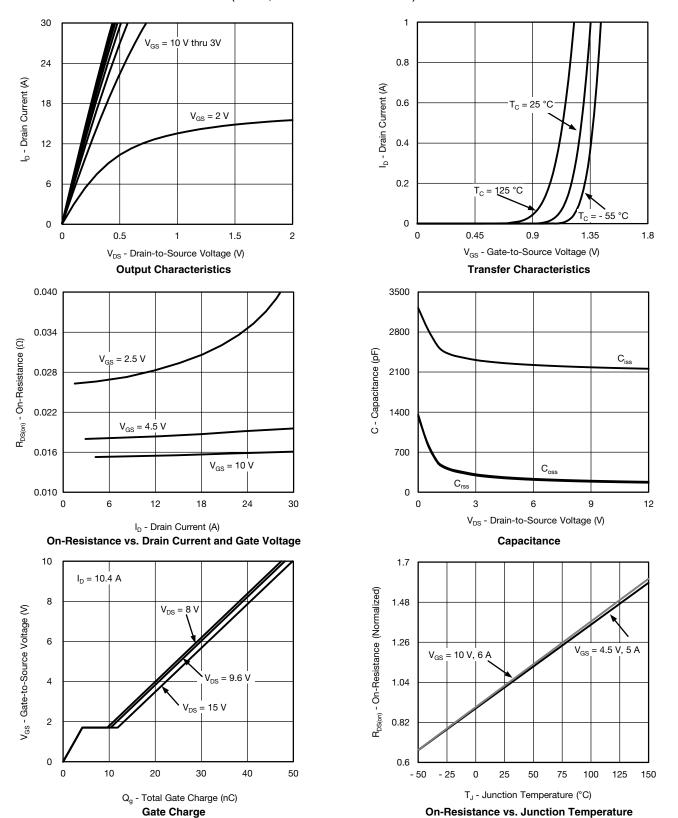
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.

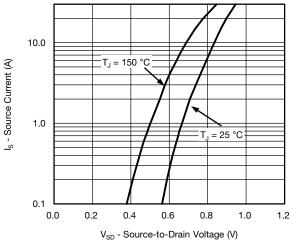
b. Guaranteed by design, not subject to production testing.



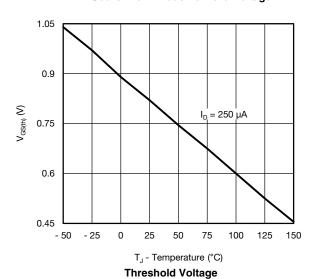
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

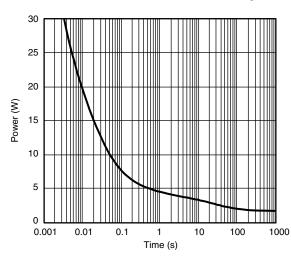




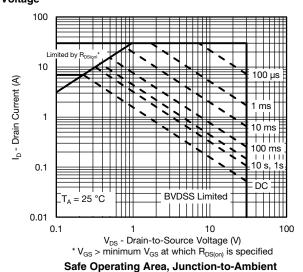


0.05 $I_D = 6 A$ 0.04 R_{DS(on)} - On-Resistance (Ω) 0.03 $T_J = 125$ °C 0.02 $T_J = 25 \, ^{\circ}C$ 0.01 0 0 10 V_{GS} - Gate-to-Source Voltage (V)

On-Resistance vs. Gate-to-Source Voltage

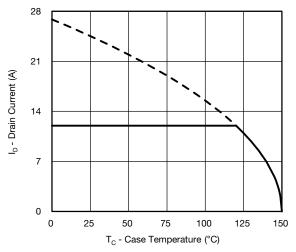


Single Pulse Power, Junction-to-Ambient

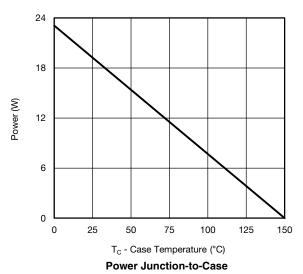


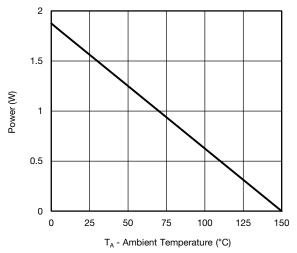


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating*



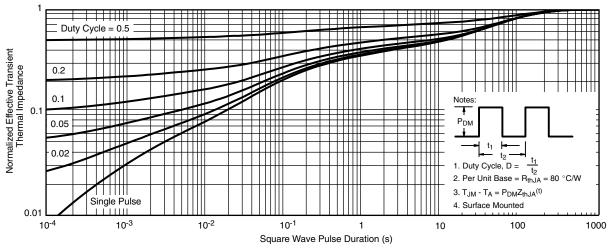


Power Junction-to-Ambient

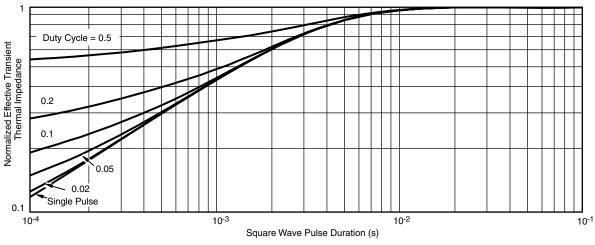
^{*} The power dissipation P_D is based on $T_{J(max.)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62644.





PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
 Package outline exclusive of mold flash and metal burr
 Package outline inclusive of plating

			SINGL	E PAD		DUAL PAD						
DIM	MILLIMETERS			INCHES			MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028
D2	0.135	0.235	0.335	0.005	0.009	0.013						
E	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041
E2	0.345	0.395	0.445	0.014	0.016	0.018						
E3	0.425	0.475	0.525	0.017	0.019	0.021						
е		0.65 BSC			0.026 BSC	;	0.65 BSC			0.026 BSC		
K		0.275 TYP		0.011 TYP		0.275 TYP		0.011 TYP				
K1		0.400 TYP		0.016 TYP		0.320 TYP		0.013 TYP				
K2		0.240 TYP		0.009 TYP		0.252 TYP		0.010 TYP				
К3		0.225 TYP		0.009 TYP					•	•		
K4		0.355 TYP		0.014 TYP								
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015
T							0.05	0.10	0.15	0.002	0.004	0.006

ECN: C-07431 - Rev. C, 06-Aug-07

DWG: 5934

06-Aug-07



RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Single



Dimensions in mm/(Inches)

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ATTLICATION NOT



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Vishay

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Revision: 02-Oct-12 Document Number: 91000